

### 20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -20 V Current -0.6A

#### **Features**

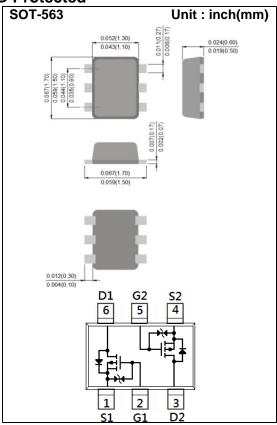
- RDS(ON), VGS@-4.5V, ID@-0.6A<340mΩ
- RDS(ON), VGS@-2.5V, ID@-0.4A<420mΩ</li>
- RDS(ON), VGS@-1.8V, ID@-0.2A<600mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-563 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0026 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 8	V
Continuous Drain Current		ID	-0.6	Α
Pulsed Drain Current		I <sub>DM</sub>	-2.4	Α
Power Dissipation	T <sub>a</sub> =25°C	_	300	mW
	Derate above 25°C	P <sub>D</sub>	2.4	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance		R <sub>θJA</sub>		
- Junction to Ambient <sup>(Note 3)</sup>			417	°C/W



### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.64	-1.0	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-0.6A	-	280	340	mΩ	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.4A	-	330	420		
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-0.2A	-	420	600		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 3.5	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	$Q_g$	101/1	-	2.2	-	nC	
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-0.6A,	-	0.4	-		
Gate-Drain Charge	$Q_gd$	VGS=-4.5 V(Note 1,2)	-	0.5	-		
Input Capacitance	Ciss	\/ 40\/ \/ 0\/	-	151	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	27	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	9	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>		-	9	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =-10V, I <sub>D</sub> =-0.6A,	-	37	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	128	-		
Turn-Off Fall Time	tf	RG=012(Note 1,2)	-	72	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-0.4	Α	
Diode Forward Voltage	V <sub>SD</sub>	Is=-1A, V <sub>GS</sub> =0V	-	-0.95	-1.2	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited

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#### **TYPICAL CHARACTERISTIC CURVES**

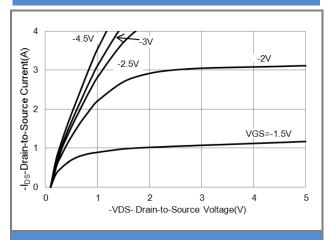


Fig.1 On-Region Characteristics

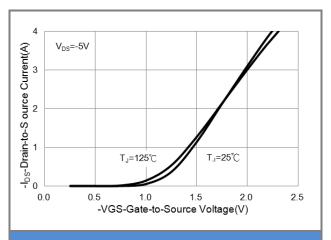


Fig.2 Transfer Characteristics

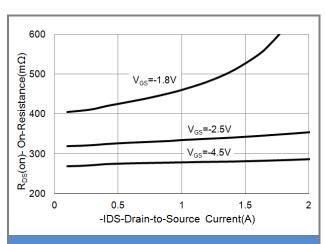


Fig.3 On-Resistance vs. Drain Current

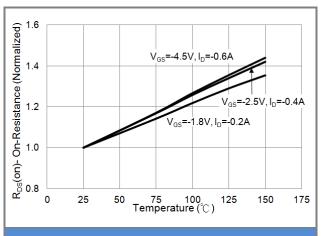
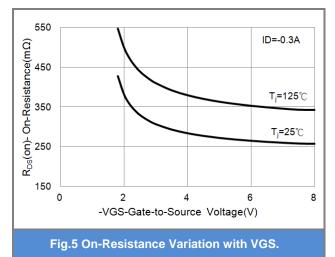


Fig.4 On-Resistance vs. Junction temperature



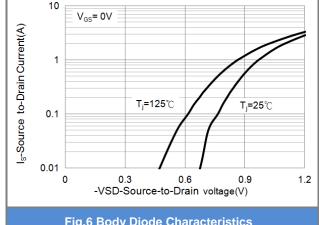


Fig.6 Body Diode Characteristics



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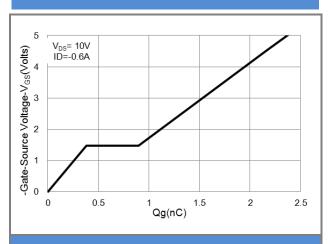


Fig.7 Gate-Charge Characteristics

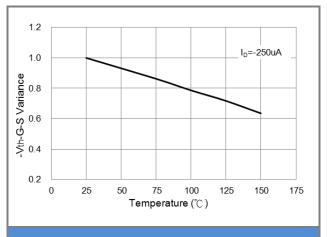


Fig.8 Threshold Voltage Variation with Temperature

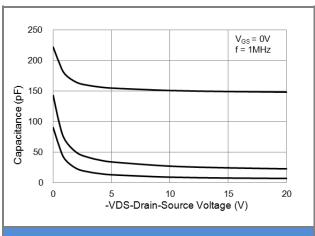


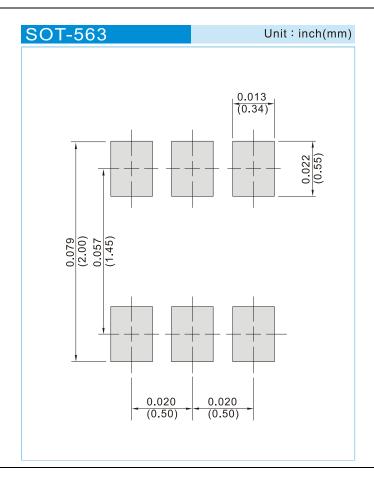
Fig.9 Capacitance vs. Drain-Source Voltage



## **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJX8803	SOT-563	4K pcs / 7" reel	X03	
PJX8803	SOT-563	10K pcs / 13" reel	X03	
PJX8803	SOT-563	8K pcs / 7" reel	X03	
PJX8803	SOT-563	20K pcs / 13" reel	X03	

## **Mounting Pad Layout**





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